International **TOR** Rectifier

August, 27th 2009 Automotive grade

AUIPS7141R

100m Ω max.

65V

20A min.

CURRENT SENSE HIGH SIDE SWITCH

Product Summary

Current shutdown

Rds(on)

Vclamp

Features

- Suitable for 24V systems
- Over current shutdown
- Over temperature shutdown
- Current sensing
- Active clamp
- Low current
- ESD protection
- Optimized Turn On/Off for EMI

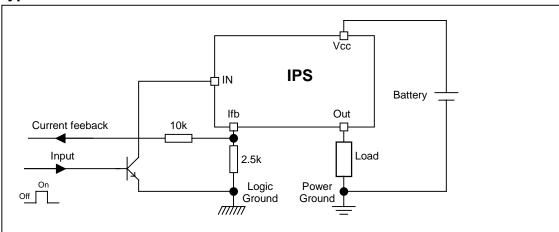
Applications

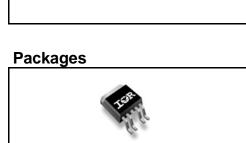
- 21W Filament lamp
- Solenoid
- 24V loads for trucks

Description

The AUIPS7141R is a fully protected four terminal high side switch specifically designed for driving lamp. It features current sensing, over-current, over-temperature, ESD protection and drain to source active clamp. When the input voltage Vcc - Vin is higher than the specified threshold, the output power Mosfet is turned on. When the Vcc - Vin is lower than the specified Vil threshold, the output Mosfet is turned off. The Ifb pin is used for current sensing. The over-current shutdown is higher than inrush current of the lamp.

Typical Connection





DPak

Qualification Information[†]

Qualification Level		Comments: This family of ICs ha	Automotive (per AEC-Q100 ^{††}) Comments: This family of ICs has passed an Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.				
Moisture	Sensitivity Level	DPAK-5L	MSL1, 260°C (per IPC/JEDEC J-STD-020)				
	Machine Model		Class M2 (200 V) (per AEC-Q100-003)				
ESD	Human Body Model		Class H1C (1500 V) (per AEC-Q100-002)				
	Charged Device Model	Class C5 (1000 V) (per AEC-Q100-011)					
IC Latch-	Up Test	Class II, Level A (per AEC-Q100-004)					
RoHS Co	mpliant		Yes				

† Qualification standards can be found at International Rectifier's web site http://www.irf.com/

t+ Exceptions to AEC-Q100 requirements are noted in the qualification report.

+++ Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.

Absolute Maximum Ratings Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. (Tambient=25°C unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
Vout	Maximum output voltage	Vcc-60	Vcc+0.3	V
Vcc-Vin max.	Maximum Vcc voltage	-16	60	V
lifb, max.	Maximum feedback current	-50	10	mA
Vcc sc.	Maximum Vcc voltage with short circuit protection see page 7		50	V
Pd	Maximum power dissipation (internally limited by thermal protection)			W
FU	Rth=50°C/W DPack 6cm ² footprint		2.5	vv
Tj max.	Max. storage & operating junction temperature	-40	150	°C

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
Rth1	Thermal resistance junction to ambient DPak Std footprint	70	_	
Rth2	Thermal resistance junction to ambient Dpak 6cm ² footprint	50	_	°C/W
Rth3	Thermal resistance junction to case Dpak	4	_	

Recommended Operating Conditions

Symbol	Parameter	Min.	Max.	Units
lout	Continuous output current, Tambient=85°C, Tj=125°C			Δ
	Rth=50°C/W, Dpak 6cm ² footprint	_	2.1	~
Rlfb	Ifb resistor	1.5	-	kΩ

Static Electrical Characteristics

Tj=25°C, Vcc=28V (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Vcc op.	Operating voltage	6	_	60	V	
Rds(on)	ON state resistance Tj=25°C	—	75	100	mΩ	lds=2A
	ON state resistance Tj=150°C(2)	_	135	180	1115.2	ius=2A
Icc off	Supply leakage current	_	1	3		Vin=Vcc / Vifb=Vgnd
lout off	Output leakage current	_	1	3	μA	Vout=Vgnd
l in on	Input current while on	0.6	1.6	3	mA	Vcc-Vin=28V
V clamp1	Vcc to Vout clamp voltage 1	60	64	_		Id=10mA
V clamp2	Vcc to Vout clamp voltage 2	60	65	72		Id=6A see fig. 2
Vih(1)	High level Input threshold voltage	—	3	4.5	V	Id=10mA
Vil(1)	Low level Input threshold voltage	1.5	2.3	—	v	
Vf	Forward body diode voltage Tj=25°C	_	0.8	0.9		lf=1A
	Forward body diode voltage Tj=125°C	_	0.65	0.75		

(1) Input thresholds are measured directly between the input pin and the tab.

Switching Electrical Characteristics Vcc=28V, Resistive load=27Ω, Tj=25°C

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
tdon	Turn on delay time to 20%	4	10	20	110	
tr	Rise time from 20% to 80% of Vcc	2	5	10	μs	See fig. 1
tdoff	Turn off delay time	20	40	80	110	See lig. I
tf	Fall time from 80% to 20% of Vcc	2.5	5	10	μs	

Protection Characteristics

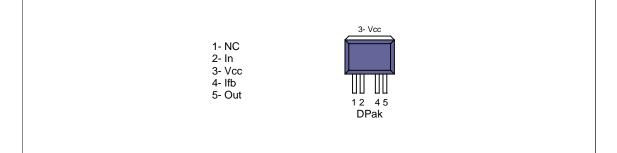
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Tsd	Over temperature threshold	150(2)	165	_	°C	See fig. 3 and fig.11
lsd	Over-current shutdown	20	25	35	А	See fig. 3 and page 6
I fault	Ifb after an over-current or an over- temperature (latched)	2.7	3.3	4	mA	See fig. 3

Current Sensing Characteristics

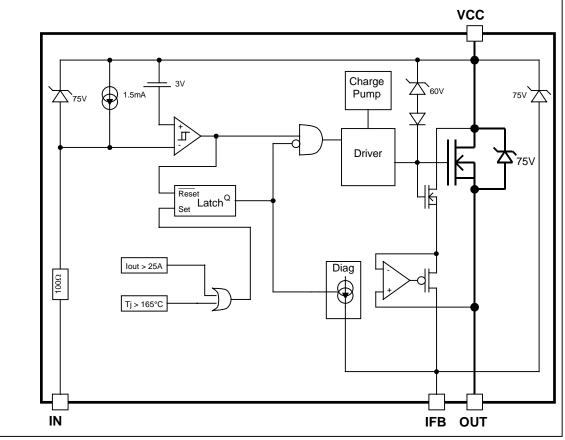
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Ratio	I load / Ifb current ratio	2000	2400	2800		Iload=2A
Ratio_TC	I load / Ifb variation over temperature(2)	-5%	0	+5	%	Tj=-40°C to +150°C
I offset	Load current offset	-0.2	0	0.2	A	lout<2A
Ifb leakage	Ifb leakage current On in open load	0	8	100	μA	lout=0A

(2) Guaranteed by design

Lead Assignments



Functional Block Diagram All values are typical



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Truth Table

Op. Conditions	Input	Output	Ifb pin voltage
Normal mode	Н	L	0V
Normal mode	L	Н	I load x Rfb / Ratio
Open load	Н	L	0V
Open load	L	Н	0V
Short circuit to GND	Н	L	0V
Short circuit to GND	L	L	V fault (latched)
Over temperature	Н	L	0V
Over temperature	L	L	V fault (latched)

Operating voltage

Maximum Vcc voltage : this is the maximum voltage before the breakdown of the IC process.

Operating voltage . This is the Vcc range in which the functionality of the part is guaranteed. The AEC-Q100 gualification is run at the maximum operating voltage specified in the datasheet.

Reverse battery

During the reverse battery the Mosfet is kept off and the load current is flowing into the body diode of the power Mosfet. Power dissipation in the IPS : P = I load * Vf

If the power dissipation is too high in Rifb, a diode in serial can be added to block the current.

The transistor used to pull-down the input should be a bipolar in order to block the reverse current. The 100ohm input resistor can not sustain continuously 16V (see Vcc-Vin max, in the Absolute Maximum Ratings section)

Active clamp

The purpose of the active clamp is to limit the voltage across the MOSFET to a value below the body diode break down voltage to reduce the amount of stress on the device during switching.

The temperature increase during active clamp can be estimated as follows:

$$\Delta_{Tj} = \mathbf{P}_{CL} \cdot \mathbf{Z}_{TH}(\mathbf{t}_{CLAMP})$$

Where: $Z_{TH}(t_{CLAMP})$ is the thermal impedance at t_{CLAMP} and can be read from the thermal impedance curves given in the data sheets.

 $P_{CL} = V_{CL} \cdot I_{CLava}$: Power dissipation during active clamp

 $V_{\rm CL}$ = 65V : Typical V_{CLAMP} value.

 $I_{CLavg} = \frac{I_{CL}}{2}$: Average current during active clamp $t_{\text{CL}} = \frac{I_{\text{CL}}}{\left|\frac{di}{dt}\right|} \text{: Active clamp duration}$ $\frac{di}{dt} = \frac{V_{\text{Battery}} - V_{\text{CL}}}{I}$: Demagnetization current

Figure 9 gives the maximum inductance versus the load current in the worst case : the part switches off after an over temperature detection. If the load inductance exceeds the curve, a free wheeling diode is required.

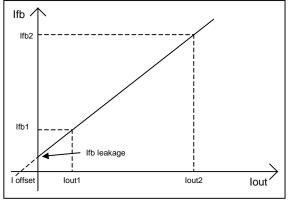
Over-current protection

The threshold of the over-current protection is set in order to guarantee that the device is able to turn on a load with an inrush current lower than the minimum of Isd. Nevertheless for high current and high temperature the device may switch off for a lower current due to the over-temperature protection. This behavior is shown in Figure 11.

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Current sensing accuracy



The current sensing is specified by measuring 3 points :

- Ifb1 for lout1

- Ifb2 for lout2

- Ifb leakage for lout=0

The parameters in the datasheet are computed with the following formula :

Ratio = (lout2 - lout1)/(lfb2 - lfb1)

I offset = Ifb1 x Ratio – lout1

This allows the designer to evaluate the lfb for any lout value using :

Ifb = (lout + I offset) / Ratio if Ifb > Ifb leakage

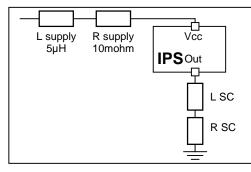
For some applications, a calibration is required. In that case, the accuracy of the system will depends on the variation of the I offset and the ratio over the temperature range. The ratio variation is given by Ratio_TC specified in page 4. The loffset variation depends directly on the Rdson :

I offset@-40°C= I offset@25°C / 0.8

I offset@150°C= I offset@25°C / 1.9

Maximum Vcc voltage with short circuit protection

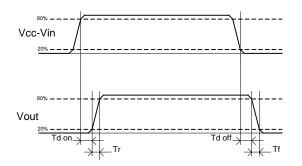
The maximum Vcc voltage with short circuit is the maximum voltage for which the part is able to protect itself under test conditions representative of the application. 2 kind of short circuits are considered : terminal and load short circuit.



	L SC	R SC
Terminal SC	0.1 µH	10 mohm
Load SC	10 µH	100 mohm

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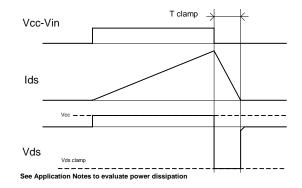


Figure 1 – IN rise time & switching definitions

Figure 2 – Active clamp waveforms

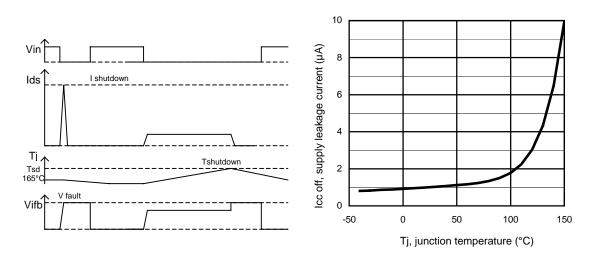


Figure 3 – Protection timing diagram

Figure 4 – Icc off (µA) Vs Tj (°C)

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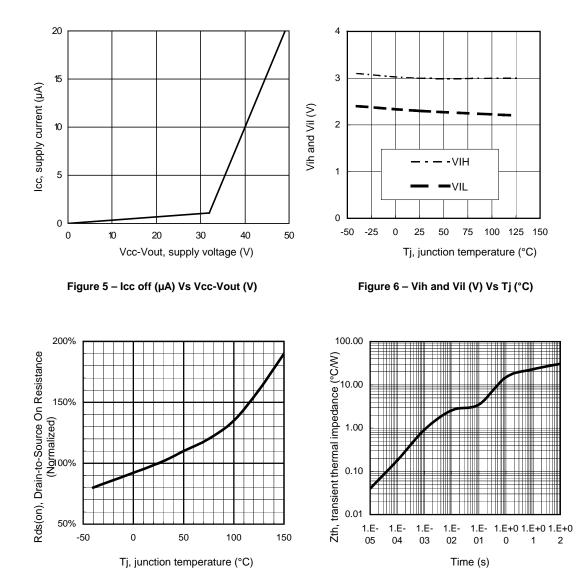
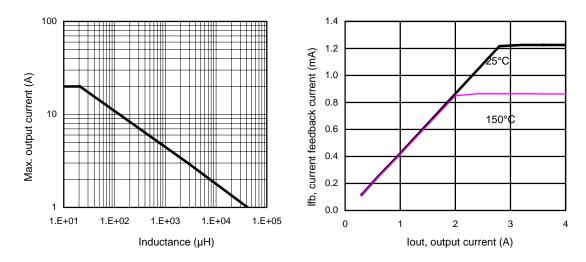


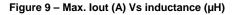
Figure 7 - Normalized Rds(on) (%) Vs Tj (°C)

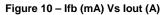
Figure 8 – Transient thermal impedance (°C/W) Vs time (s)

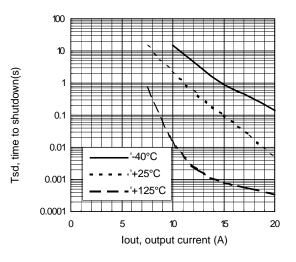
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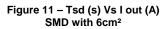
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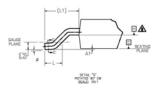


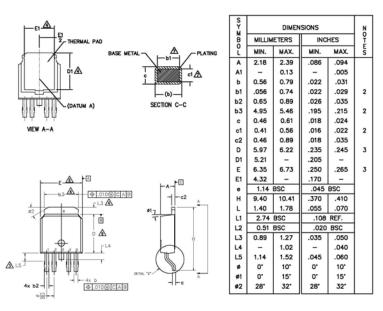


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Case Outline 5 Lead – DPAK





NOTES:

1.- DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M-1994

2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].

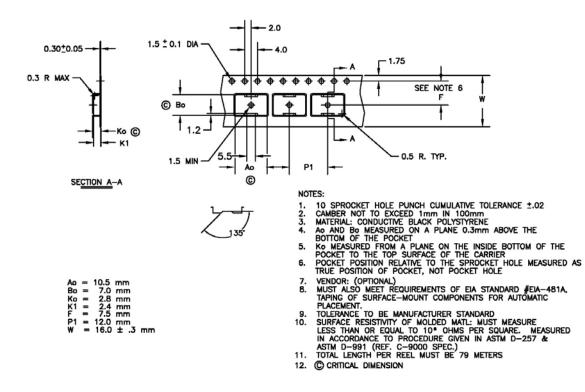
A- LEAD DIMENSION UNCONTROLLED IN L5.

- A- dimension d1, e1, l3 & b3 establish a minimum mounting surface for thermal pad.
- 5.- SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- ▲ DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- A- DIMENSION 51 & c1 APPLIED TO BASE METAL ONLY.
- 8.- DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-252.
- 10. LEADS AND DRAIN ARE PLATED WITH 100% Sn

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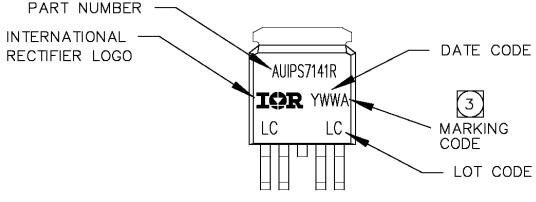
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Tape & Reel 5 Lead – DPAK



Part Marking Information

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Ordering Information

Base Part Number	Dashawa Tana	Standard Pack		Occurrente (a David Marrishan
Dase i alt Number	Package Type	Form	Quantity	Complete Part Number
	D-Pak-5-Lead	Tube	75	AUIPS7141R
		Tape and reel	3000	AUIPS7141RTR
AUIPS7141R		Tape and reel left	2000	AUIPS7141RTRL
		Tape and reel right	2000	AUIPS7141RTRR

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